## 2SK1637, 2SK2422

Silicon N-Channel MOS FET

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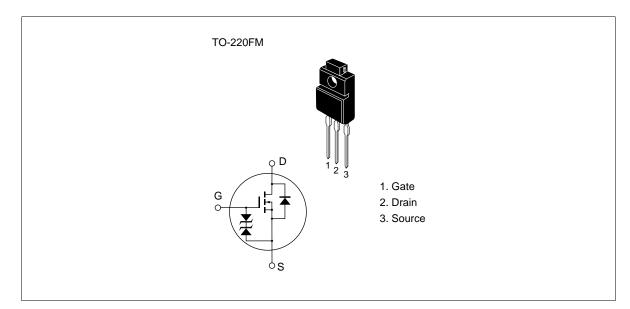
### Application

High speed power switching

### Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

### Outline





## <u>2SK1637, 2SK2422</u>

## **Absolute Maximum Ratings** (Ta = 25°C)

Item		Symbol	Ratings	Unit
Drain to source voltage	2SK1637	V <sub>DSS</sub>	600	V
	2SK2422		650	
Gate to source voltage		V <sub>GSS</sub>	±30	V
Drain current		I <sub>D</sub>	4	А
Drain peak current		L *1 D(pulse)	16	А
Body to drain diode reverse drain current		I <sub>DR</sub>	4	А
Channel dissipation		Pch*2	35	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

Note 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at T<sub>c</sub> =  $25^{\circ}C$ 

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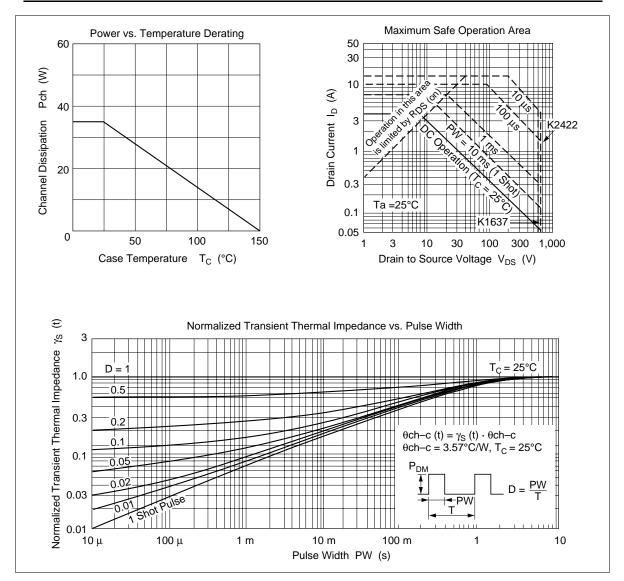
Item		Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source	2SK1637	$V_{(\text{BR})\text{DSS}}$	600	—	_	V	$I_{\rm D} = 10 \text{ mA}, V_{\rm GS} = 0$
breakdown voltage	2SK2422	-	650	_			
Gate to source breakdown voltage		$V_{(BR)GSS}$	±30	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current		I <sub>GSS</sub>	—	—	±10	μA	$V_{\text{GS}} = \pm 25 \text{ V},  V_{\text{DS}} = 0$
Zero gate voltage	2SK1637	I <sub>DSS</sub>	—	—	250	μA	$V_{\rm DS} = 500 \text{ V}, V_{\rm GS} = 0$
drain current	2SK2422	-					$V_{\rm DS} = 550 \text{ V}, \text{ V}_{\rm GS} = 0$
Gate to source cutoff	voltage	$V_{GS(off)}$	2.0	_	3.0	V	$I_{\rm D} = 1 \text{ mA}, V_{\rm DS} = 10 \text{ V}$
Static Drain to source	2SK1637	$R_{\text{DS(on)}}$	—	1.8	2.4	Ω	$I_{\rm D} = 2$ A, $V_{\rm GS} = 10$ V * <sup>1</sup>
on state resistance	2SK2422	-	—	2.0	2.6	-	
Forward transfer admi	ittance	yfs	2.2	3.5	_	S	$I_{\rm D} = 2$ A, $V_{\rm DS} = 10$ V * <sup>1</sup>
Input capacitance		Ciss	—	600	_	pF	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0,$
Output capacitance		Coss	—	140	—	pF	f = 1 MHz
Reverse transfer capacitance		Crss	—	25	—	pF	
Turn-on delay time		t <sub>d(on)</sub>	—	8	_	ns	$I_{\rm D} = 2$ A, $V_{\rm GS} = 10$ V,
Rise time		t,	—	30	_	ns	$R_{L} = 15 \Omega$
Turn-off delay time		t <sub>d(off)</sub>	_	60	_	ns	
Fall time		t <sub>f</sub>		35	_	ns	-
Body to drain diode fo voltage	rward	$V_{DF}$	_	0.9	_	V	$I_{F} = 4 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time		t <sub>rr</sub>	—	300	_	ns	$I_F = 4 \text{ A}, V_{GS} = 0,$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

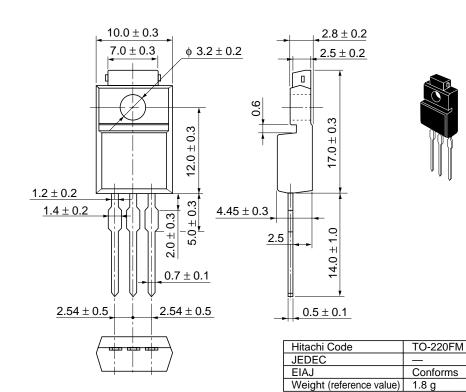
## **Electrical Characteristics** (Ta = 25°C)

Note 1. Pulse test

See characteristics curves of 2SK1402, 2SK1402A.

## 2SK1637, 2SK2422





Unit: mm

#### Cautions

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#### Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 URL NorthAmerica : http:semiconductor.hitachi.com/

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#### For further information write to: Hitachi Semiconductor Hitachi Europe GmbH

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223

Electronic components Group Domacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322 Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180 Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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